

SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

Product Summary

V _{(BR)DSS}	Max R _{DS(on)}	Max I _D T _A = +25°C
60V	1Ω @ $V_{GS} = 10V$	1A

Features and Benefits

- Repetitive avalanche rating
- No transient protection required
- Characterized for 5V logic drive
- Lead-Free Finish; RoHS Compliant (Notes 1& 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

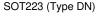
Description and Applications

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Automotive relay drivers
- Stepper motor drivers

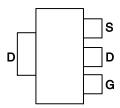
Mechanical Data

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.112 grams (Approximate)

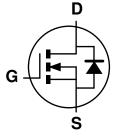




Top View



Pin Out Top View



Equivalent Circuit

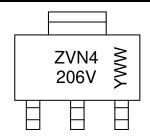
Ordering Information (Note 4)

Part Number	Packago	Packing		
Part Number	Раскаде	Qty.	Carrier	
ZVN4206GVTA	SOT223 (Type DN)	1,000	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



ZVN4206V = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 1= 2021) WW or $\overline{W}W$ = Week Code (01~53)



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	60	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	Ι _D	1	Α
Pulsed Drain Current	I _{DM}	8	Α
Continuous Drain Current	Ι _D	1	Α
Continuous Body Diode Current	I _{SD}	600	mA
Avalanche Current - Repetitive	I _{AR}	600	mA
Avalanche Energy - Repetitive	E_{AR}	15	mJ

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T _A = +25°C	P _{tot}	2	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

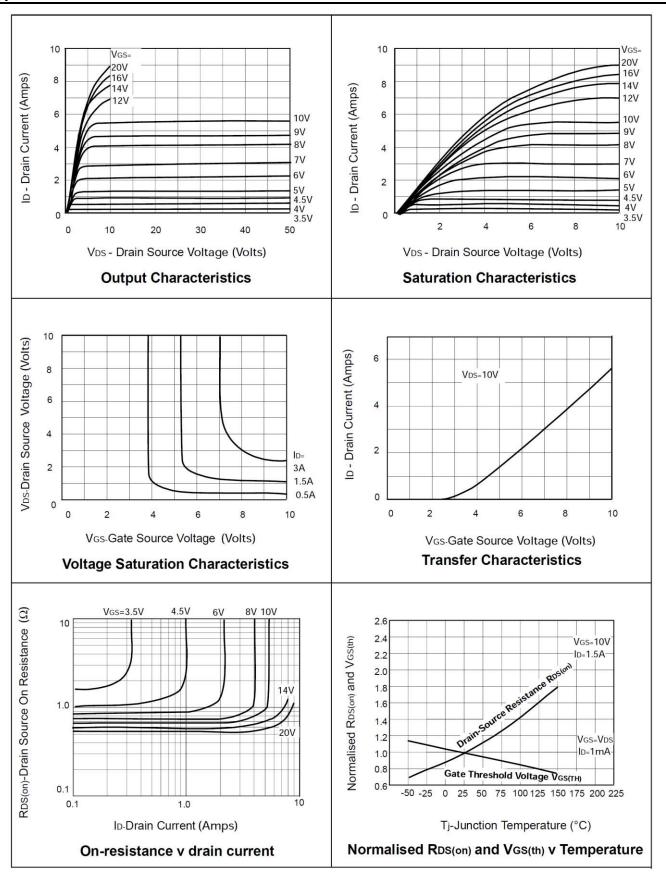
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS	OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$I_D = 1mA$, $V_{GS} = 0V$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	10 100	μA	$V_{DS} = 60V$, $V_{GS} = 0V$ $V_{DS} = 48V$, $V_{GS} = 0V$, $T_{=+125}^{\circ}C$ (Note 6)	
Gate-Body Leakage	I _{GSS}	_	_	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
Gate-Source Threshold Voltage	V _{GS(th)}	1.3	_	3	V	$I_D = 1 \text{mA}, V_{DS} = V_{GS}$	
On-State Drain Current (Note 5)	I _{D(on)}	3	_	_	Α	V _{DS} = 25V, V _{GS} = 10V	
Static Drain-Source On-State Resistance (Note 5)	D	_	_	1	Ω	$V_{GS} = 10V, I_D = 1.5A$	
Static Drain-Source On-State Resistance (Note 5)	R _{DS} (ON)	_	_	1.5		$V_{GS} = 5V, I_D = 0.5A$	
Forward Transconductance (Notes 5 & 6)	9fs	300	_	_	ms	$V_{DS} = 25V, I_D = 1.5A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance (Note 6)	C _{iss}	_	_	100	pF	V 05 V V 0V	
Output Capacitance (Note 6)	Coss	_	_	60	pF	$-V_{DS} = 25 \text{ V}, V_{GS} = 0V$ - $f = 1MHz$	
Reverse Transfer Capacitance (Note 6)	Crss	_	_	20	pF		
Turn-On Delay Time (Notes 6 & 7)	t _{d(on)}	_	_	8	ns	$V_{DD} \approx 25V, V_{GEN} = 10V$ $I_{D} = 1.5A$	
Turn-On Rise Time (Notes 6 & 7)	t _r	_	_	12	ns		
Turn-Off Delay Time (Notes 6 & 7)	t _{d(off)}	_	_	12	ns		
Turn-Off Fall Time (Notes 6 & 7)	t _f	_	_	15	ns		

Notes:

- 5. Measured under pulsed conditions. Width=300µs. Duty cycle ≤ 2%.
- 6. Sample test.
 7. Switching times measured with 50 Ω source impedance and <5ns rise time on a pulse generator.

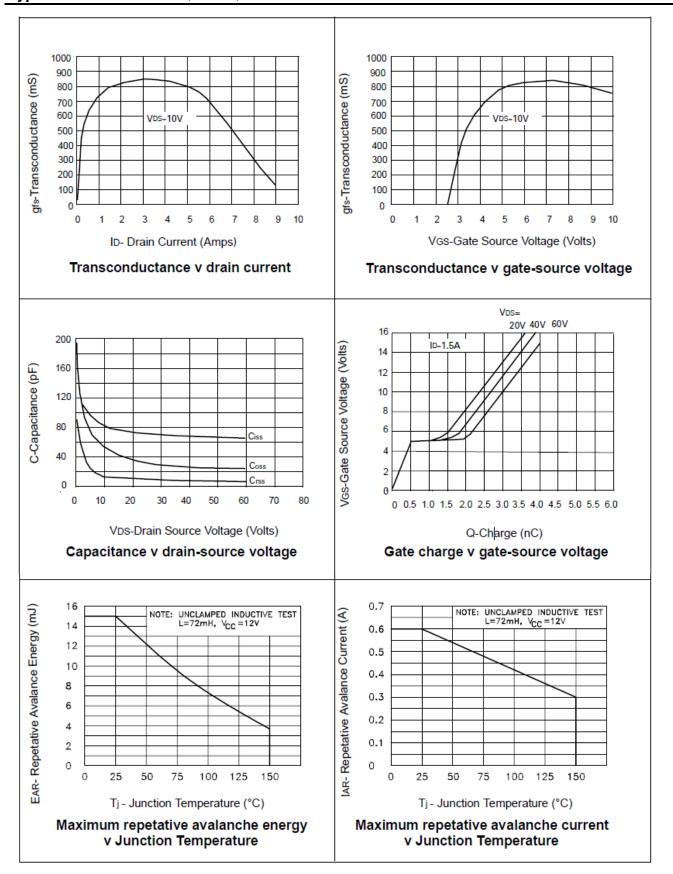


Typical Characteristics





Typical Characteristics (continued)

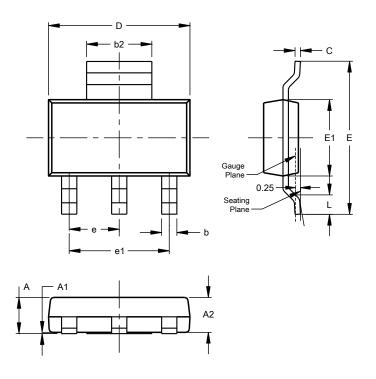




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

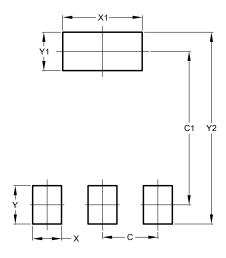


SOT223 (Type DN)				
Dim	Min	Max	Тур	
Α		1.70		
A1	0.01	0.15		
A2	1.50	1.68	1.60	
b	0.60	0.80	0.70	
b2	2.90	3.10		
C	0.20	0.32		
D	6.30	6.70		
Е	6.70	7.30		
E1	3.30	3.70		
е			2.30	
e1			4.60	
L	0.85			
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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